

**MOTOROLA**

查询 "MRF949_D" 供应商

NPN Silicon Low Noise Transistors

Motorola's MRF949 is a high performance NPN transistor designed for use in high gain, low noise small-signal amplifiers. The MRF949 is well suited for low voltage wireless applications. This device features a 9.0 GHz DC current gain-bandwidth product with excellent linearity.

- Low Noise Figure, $NF_{min} = 1.4$ dB (Typ) @ 1.0 GHz, 8.0 V, 3.0 mA
- High Current Gain-Bandwidth Product, $f_T = 9.0$ GHz, 6.0 V, 15 mA
- Maximum Stable Gain, 19 dB @ 1.0 GHz, 6.0 V, 10 mA
- Output Third Order Intercept, Output $IP_3 = 29$ dBm @ 1.0 GHz, 6.0 V, 10 mA
- Fully Ion-Implanted with Gold Metallization and Nitride Passivation

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	10	Vdc
Collector-Base Voltage	V_{CBO}	20	Vdc
Emitter-Base Voltage	V_{EBO}	1.5	Vdc
Power Dissipation @ $T_C = 75^\circ\text{C}$ Derate linearly above $T_C = 75^\circ\text{C}$ at	$P_{D(max)}$	0.144 1.92	W mW/ $^\circ\text{C}$
Collector Current – Continuous [Note 3]	I_C	50	mA
Storage Temperature	T_{stg}	-55 to 150	$^\circ\text{C}$
Maximum Junction Temperature	$T_{J(max)}$	150	$^\circ\text{C}$

NOTES: 1. Meets Human Body Model (HBM) ≤ 300 V and Machine Model (MM) ≤ 75 V.
2. ESD data available upon request.
3. For MTBF >10 years.

THERMAL CHARACTERISTIC

Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	520	$^\circ\text{C/W}$

NOTE: To calculate the junction temperature use $T_J = (P_D \times R_{\theta JC}) + T_C$. The case temperature measured on collector lead adjacent to the package body.

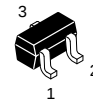
MRF949T1

LOW NOISE TRANSISTORS

 $f_T = 9.0$ GHz $NF_{min} = 1.4$ dB $I_{C MAX} = 50$ mA $V_{CEO} = 10$ V

SEMICONDUCTOR
TECHNICAL DATA

- Pin 1. Base
2. Emitter
3. Collector



PLASTIC PACKAGE
CASE 463
(SC-90/SC-75, Tape & Reel Only)

ORDERING INFORMATION

Device	Marking	Package
MRF949T1	JL	SC-90/SC75 Tape & Reel*

*3,000 Units per 8 mm, 7 inch reel.

LIFETIME BUY

LAST ORDER 25SEP01 LAST SHIP 26MAR02

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$, unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS [Note 1]

Collector–Emitter Breakdown Voltage ($I_C = 0.1\text{ mA}$, $I_B = 0$)	$V_{(BR)CEO}$	10	12	–	Vdc
Collector–Base Breakdown Voltage ($I_C = 0.1\text{ mA}$, $I_E = 0$)	$V_{(BR)CBO}$	20	23	–	Vdc
Emitter Cutoff Current ($V_{EB} = 1.0\text{ V}$, $I_C = 0$)	I_{EBO}	–	–	0.1	μA
Collector Cutoff Current ($V_{CB} = 10\text{ V}$, $I_E = 0$)	I_{CBO}	–	–	0.1	μA

ON CHARACTERISTICS [Note 1]

DC Current Gain ($V_{CE} = 6.0\text{ V}$, $I_C = 5.0\text{ mA}$)	h_{FE}	50	–	–	–
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DYNAMIC CHARACTERISTICS

Collector–Base Capacitance ($V_{CB} = 1.0\text{ V}$, $I_E = 0$, $f = 1.0\text{ MHz}$) ($V_{CB} = 5.0\text{ V}$, $I_E = 0$, $f = 1.0\text{ MHz}$)	C_{cb}	– –	0.4 0.3	– –	pF
Current–Gain Bandwidth Product ($V_{CE} = 6.0\text{ V}$, $I_C = 30\text{ mA}$, $f = 1.0\text{ GHz}$)	f_t	–	9.0	–	GHz

PERFORMANCE CHARACTERISTICS

Insertion Gain ($V_{CE} = 1.0\text{ V}$, $I_C = 1.0\text{ mA}$, $f = 1.0\text{ GHz}$) ($V_{CE} = 6.0\text{ V}$, $I_C = 15\text{ mA}$, $f = 1.0\text{ GHz}$)	$ S_{21} ^2$	– –	7.0 15	– –	dB
Maximum Unilateral Gain [Note 2] ($V_{CE} = 1.0\text{ V}$, $I_C = 1.0\text{ mA}$, $f = 1.0\text{ GHz}$) ($V_{CE} = 6.0\text{ V}$, $I_C = 15\text{ mA}$, $f = 1.0\text{ GHz}$)	G_{Umax}	– –	13 17	– –	dB
Maximum Stable Gain and/or Maximum Available Gain [Note 3] ($V_{CE} = 1.0\text{ V}$, $I_C = 1.0\text{ mA}$, $f = 1.0\text{ GHz}$) ($V_{CE} = 6.0\text{ V}$, $I_C = 15\text{ mA}$, $f = 1.0\text{ GHz}$)	MSG MAG	– –	12 18	– –	dB
Noise Figure – Minimum ($V_{CE} = 1.0\text{ V}$, $I_C = 1.0\text{ mA}$, $f = 1.0\text{ GHz}$) ($V_{CE} = 6.0\text{ V}$, $I_C = 5.0\text{ mA}$, $f = 1.0\text{ GHz}$)	NF_{min}	– –	1.6 1.4	– –	dB
Noise Resistance ($V_{CE} = 1.0\text{ V}$, $I_C = 1.0\text{ mA}$, $f = 1.0\text{ GHz}$) ($V_{CE} = 6.0\text{ V}$, $I_C = 5.0\text{ mA}$, $f = 1.0\text{ GHz}$)	R_N	– –	24 19	– –	Ω
Associated Gain at Minimum NF ($V_{CE} = 1.0\text{ V}$, $I_C = 1.0\text{ mA}$, $f = 1.0\text{ GHz}$) ($V_{CE} = 6.0\text{ V}$, $I_C = 5.0\text{ mA}$, $f = 1.0\text{ GHz}$)	G_{NF}	– –	10 15	– –	dB
Output Power at 1.0 dB Gain Compression [Note 4] ($V_{CE} = 6.0\text{ V}$, $I_C = 15\text{ mA}$, $f = 1.0\text{ GHz}$)	P_{1dB}	–	13	–	dBm
Output Third Order Intercept [Note 4] ($V_{CE} = 6.0\text{ V}$, $I_C = 15\text{ mA}$, $f = 1.0\text{ GHz}$)	OIP_3	–	28	–	dBm

NOTES: 1. Pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$ pulsed.

2. Maximum unilateral gain is:

$$G_{Umax} = \frac{|S_{21}|^2}{(1 - |S_{11}|^2)(1 - |S_{22}|^2)}$$

3. Maximum Available Gain and Maximum Stable Gain are defined by the K factor as follows:

$$MAG = \left| \frac{S_{21}}{S_{12}} \left(K \pm \sqrt{K^2 - 1} \right) \right|, \text{ if } K > 1, \quad MSG = \left| \frac{S_{21}}{S_{12}} \right|, \text{ if } K < 1$$

4. $Z_{in} = 50\text{ }\Omega$ and Z_{out} matched for optimum IP_3 .

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TYPICAL CHARACTERISTICS

Figure 1. Capacitance versus Voltage

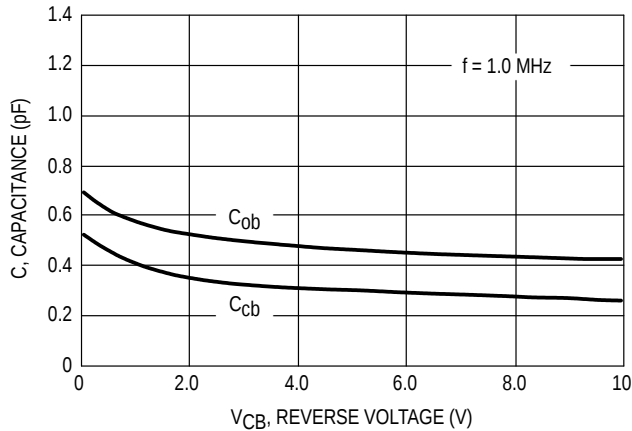


Figure 2. Input Capacitance versus Voltage

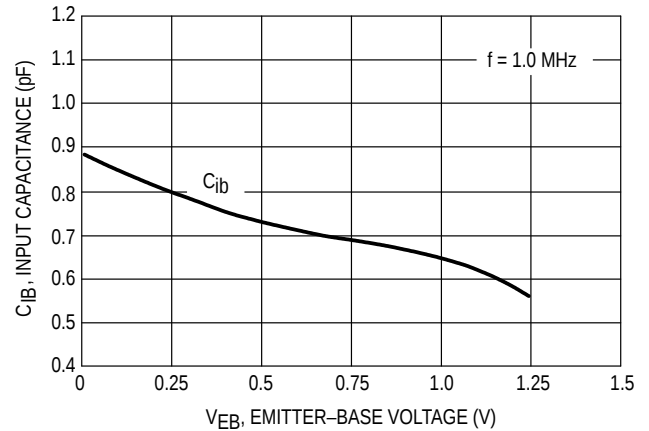


Figure 3. DC Current Gain versus Collector Current

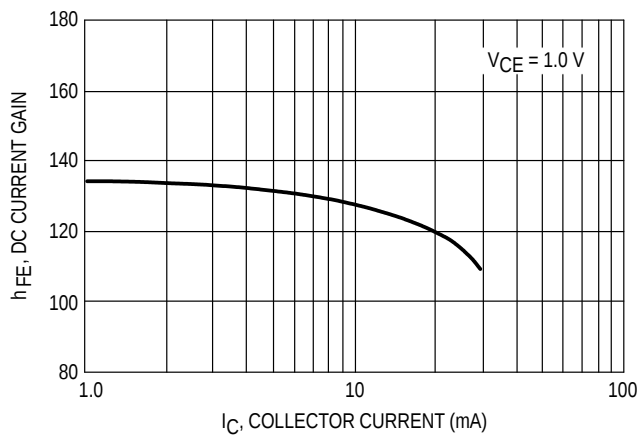


Figure 4. Gain-Bandwidth Product versus Collector Current

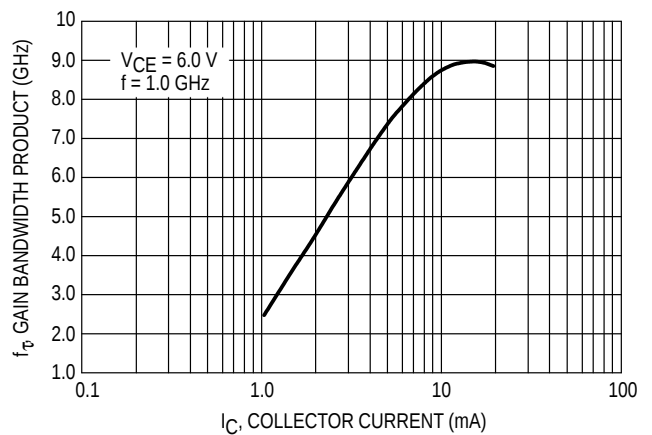
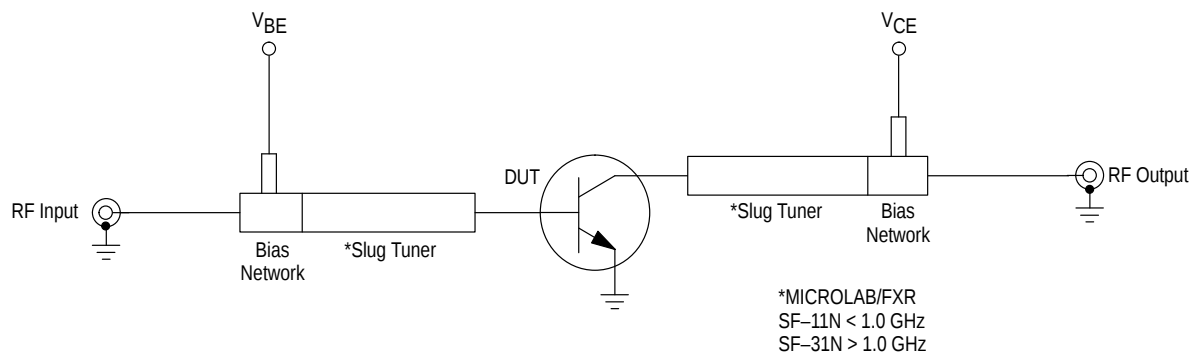


Figure 5. Functional Circuit Schematic



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TYPICAL CHARACTERISTICS

Figure 6. Maximum Stable/Available Gain versus Frequency

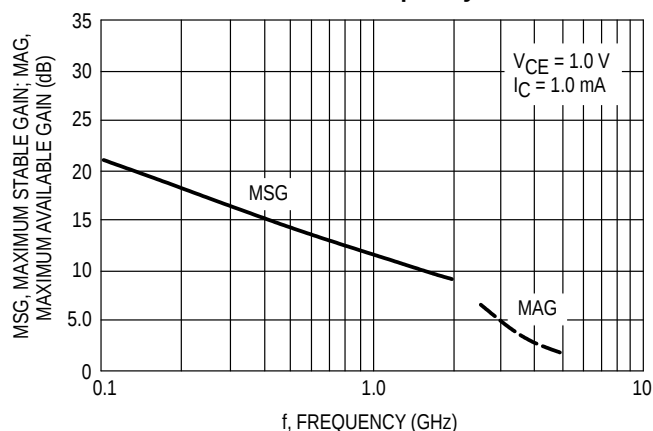


Figure 7. Maximum Stable/Available Gain versus Frequency

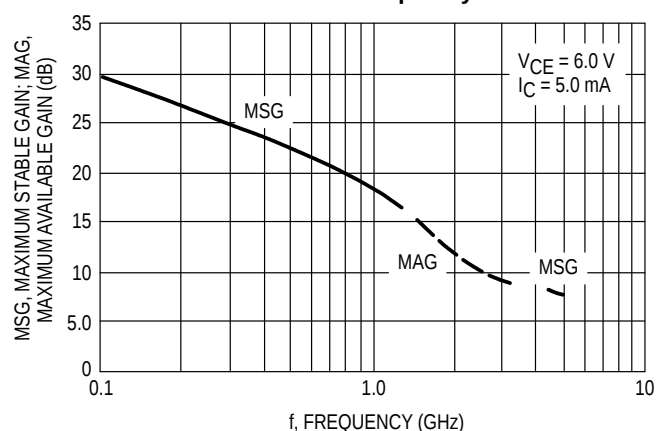


Figure 8. Maximum Unilateral Gain and Forward Insertion Gain versus Frequency

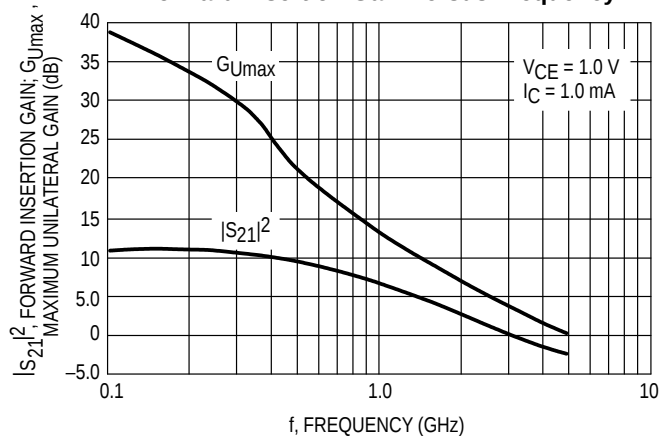


Figure 9. Maximum Unilateral Gain and Forward Insertion Gain versus Frequency

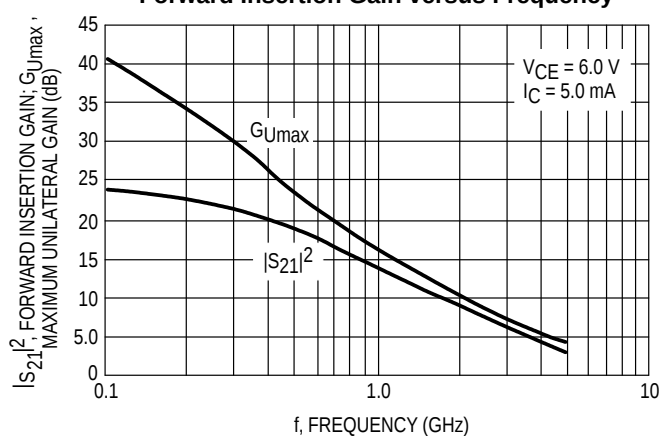


Figure 10. Maximum Unilateral Gain and Forward Insertion Gain versus Collector Current

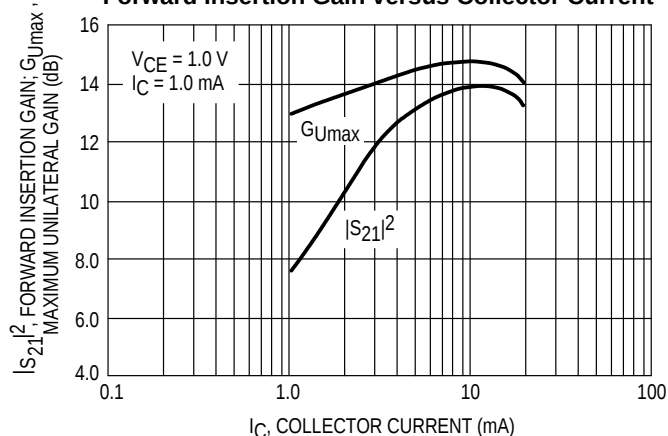
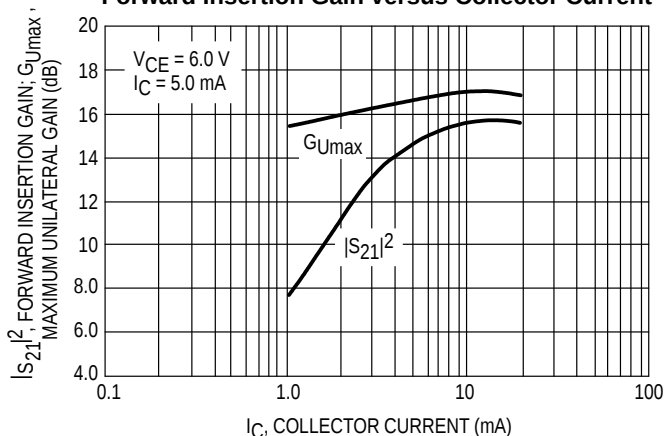


Figure 11. Maximum Unilateral Gain and Forward Insertion Gain versus Collector Current



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TYPICAL CHARACTERISTICS

Figure 12. Maximum Stable/Available Gain versus Collector Current

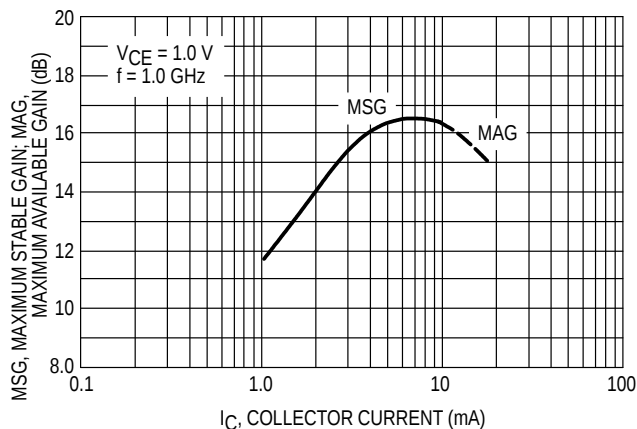


Figure 13. Maximum Stable/Available Gain versus Collector Current

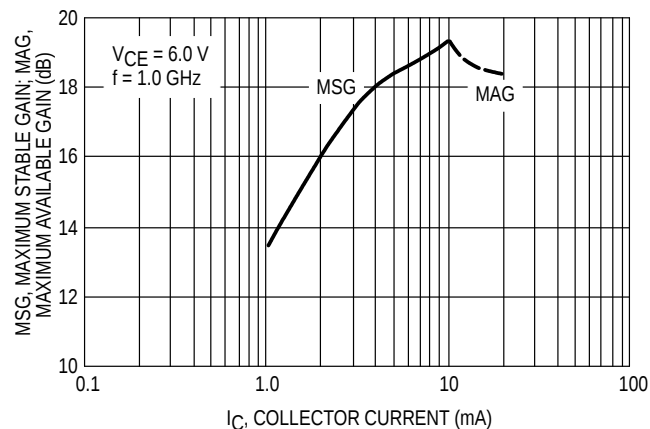


Figure 14. Minimum Noise Figure and Associated Gain versus Frequency

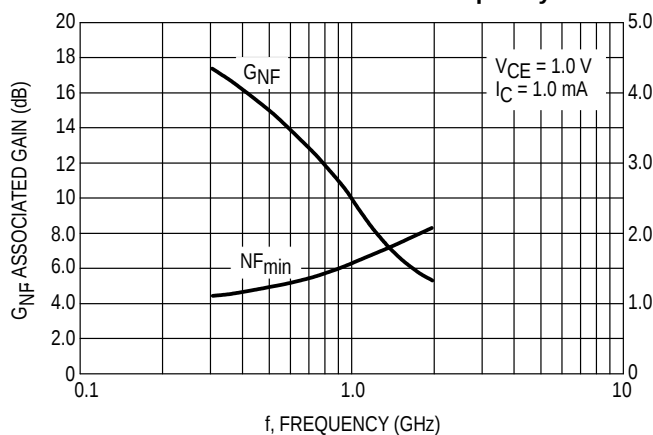


Figure 15. Minimum Noise Figure and Associated Gain versus Frequency

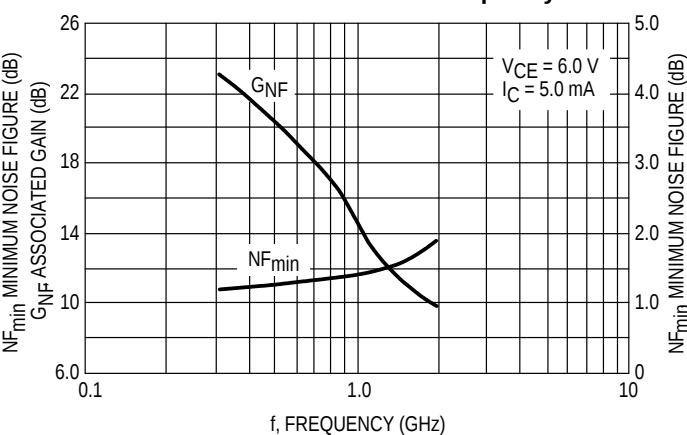


Figure 16. Minimum Noise Figure and Associated Gain versus Collector Current

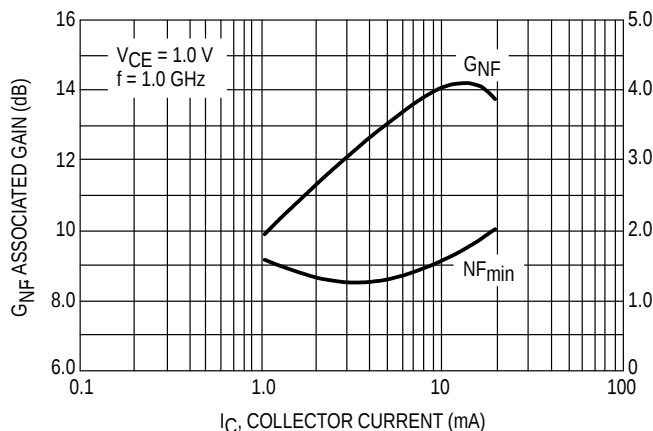
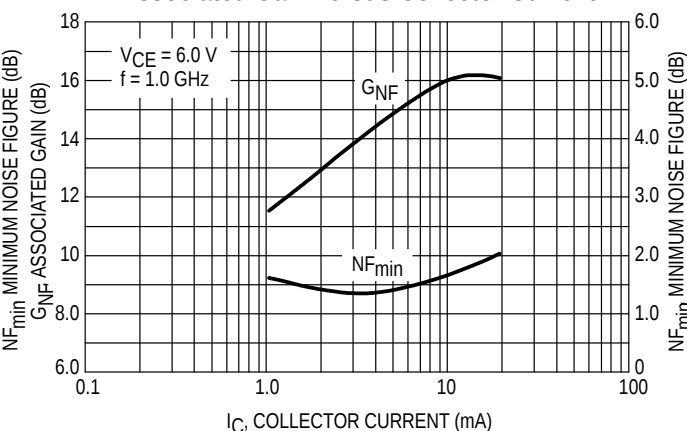


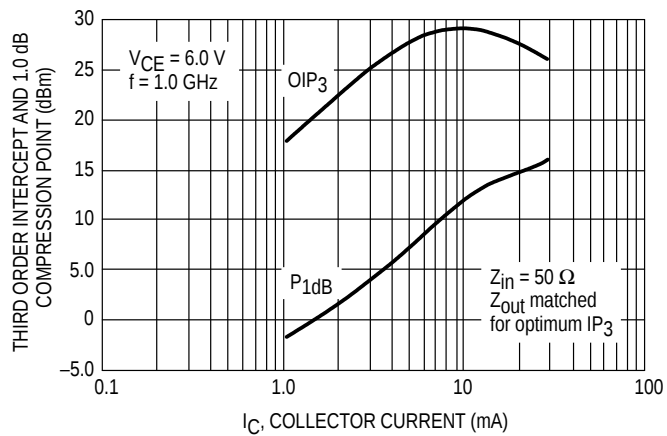
Figure 17. Minimum Noise Figure and Associated Gain versus Collector Current



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TYPICAL CHARACTERISTICS

Figure 18. Output Third Order Intercept and Output Power at 1.0 dB Gain Compression versus Collector Current



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Table 1. Common Emitter S-Parameters

查询"MRF949_D"供应商			S ₁₁		S ₂₁		S ₁₂		S ₂₂	
V _{CE} (Vdc)	I _C (mA)	f (GHz)	S ₁₁	∠ φ	S ₂₁	∠ φ	S ₁₂	∠ φ	S ₂₂	∠ φ
1.0	1.0	0.1	0.964	-12	3.62	171	0.028	82	0.989	-6
		0.3	0.926	-36	3.41	152	0.078	69	0.950	-17
		0.5	0.872	-55	2.98	135	0.115	56	0.878	-24
		0.7	0.773	-73	2.67	121	0.140	47	0.811	-31
		0.9	0.701	-89	2.40	110	0.157	40	0.751	-37
		1.0	0.672	-96	2.27	105	0.163	37	0.725	-39
		1.3	0.605	-116	1.95	90	0.172	31	0.660	-44
		1.5	0.579	-127	1.77	83	0.176	27	0.631	-48
		2.0	0.537	-152	1.43	66	0.173	24	0.584	-56
		2.5	0.521	-173	1.22	52	0.168	25	0.555	-65
		3.0	0.520	171	1.06	41	0.168	31	0.542	-74
		3.5	0.529	157	0.94	31	0.179	38	0.543	-84
		4.0	0.543	145	0.84	24	0.205	45	0.541	-95
		4.5	0.552	133	0.79	17	0.248	48	0.525	-106
		5.0	0.571	123	0.72	13	0.296	48	0.527	-117
	3.0	0.1	0.896	-20	9.79	165	0.027	79	0.960	-12
		0.3	0.780	-57	8.17	138	0.068	61	0.826	-29
		0.5	0.653	-80	6.36	120	0.089	51	0.680	-38
		0.7	0.551	-101	5.11	107	0.103	46	0.578	-43
		0.9	0.488	-117	4.23	97	0.113	43	0.510	-47
		1.0	0.468	-125	3.89	93	0.117	43	0.484	-48
		1.3	0.431	-143	3.14	82	0.128	43	0.425	-51
		1.5	0.420	-153	2.78	77	0.137	43	0.401	-54
		2.0	0.410	-174	2.16	63	0.157	44	0.364	-60
		2.5	0.415	169	1.80	52	0.179	45	0.343	-68
		3.0	0.426	157	1.55	43	0.205	46	0.332	-76
		3.5	0.439	146	1.37	34	0.234	46	0.332	-85
		4.0	0.454	137	1.24	26	0.265	45	0.329	-95
		4.5	0.470	128	1.13	19	0.302	44	0.323	-105
		5.0	0.492	119	1.05	12	0.339	41	0.324	-116
	5.0	0.1	0.831	-27	14.66	160	0.026	75	0.929	-16
		0.3	0.668	-72	10.92	129	0.059	57	0.719	-37
		0.5	0.530	-97	7.88	112	0.075	51	0.556	-44
		0.7	0.450	-118	6.06	100	0.087	49	0.458	-48
		0.9	0.409	-133	4.89	92	0.098	49	0.400	-50
		1.0	0.397	-140	4.47	88	0.103	50	0.379	-51
		1.3	0.378	-157	3.55	79	0.119	51	0.331	-53
		1.5	0.376	-166	3.12	74	0.131	51	0.312	-56
		2.0	0.378	177	2.41	62	0.159	52	0.283	-62
		2.5	0.392	162	1.99	52	0.190	51	0.266	-70
		3.0	0.402	151	1.71	43	0.221	50	0.258	-78
		3.5	0.417	141	1.51	35	0.253	48	0.257	-87
		4.0	0.433	133	1.36	27	0.286	46	0.254	-97
		4.5	0.451	125	1.25	20	0.321	43	0.250	-107
		5.0	0.469	117	1.16	13	0.356	40	0.251	-118

LIFETIME BUY

LAST ORDER 25SEP01 LAST SHIP 26MAR02

Table 1. Common Emitter S-Parameters (continued)

查询"MRF949_D"供应商			S ₁₁		S ₂₁		S ₁₂		S ₂₂	
V _{CE} (Vdc)	I _C (mA)	f (GHz)	S ₁₁	∠ φ	S ₂₁	∠ φ	S ₁₂	∠ φ	S ₂₂	∠ φ
3.0	3.0	0.1	0.909	-17	9.75	166	0.019	80	0.972	-9
		0.3	0.805	-48	8.43	142	0.051	65	0.874	-22
		0.5	0.680	-70	6.76	124	0.070	55	0.756	-29
		0.7	0.567	-89	5.55	111	0.082	51	0.669	-33
		0.9	0.490	-104	4.65	102	0.091	48	0.608	-36
		1.0	0.464	-111	4.30	98	0.095	48	0.587	-37
		1.3	0.408	-130	3.49	86	0.105	48	0.534	-39
		1.5	0.391	-141	3.10	81	0.113	48	0.513	-41
		2.0	0.366	-163	2.42	68	0.131	50	0.479	-46
		2.5	0.365	178	2.01	56	0.151	52	0.459	-52
		3.0	0.371	164	1.73	47	0.175	53	0.448	-59
		3.5	0.385	152	1.52	38	0.202	54	0.446	-67
		4.0	0.404	142	1.37	30	0.232	54	0.443	-75
		4.5	0.420	132	1.26	23	0.268	53	0.436	-83
		5.0	0.443	124	1.16	16	0.307	51	0.434	-92
	5.0	0.1	0.853	-22	14.73	162	0.019	78	0.950	-12
		0.3	0.697	-60	11.59	134	0.045	62	0.791	-27
		0.5	0.547	-82	8.62	116	0.060	56	0.652	-32
		0.7	0.447	-102	6.75	104	0.070	54	0.565	-35
		0.9	0.386	-117	5.50	96	0.080	54	0.513	-37
		1.0	0.368	-124	5.03	92	0.085	54	0.494	-37
		1.3	0.332	-142	4.02	83	0.099	55	0.453	-39
		1.5	0.323	-152	3.54	78	0.109	56	0.436	-40
		2.0	0.315	-173	2.74	66	0.134	57	0.408	-45
		2.5	0.323	170	2.26	56	0.161	57	0.392	-51
		3.0	0.334	158	1.93	47	0.189	56	0.384	-58
		3.5	0.348	147	1.70	38	0.218	55	0.380	-65
		4.0	0.369	138	1.53	31	0.249	53	0.376	-73
		4.5	0.387	130	1.40	24	0.283	51	0.371	-81
		5.0	0.410	122	1.30	17	0.319	49	0.367	-89
	10.0	0.1	0.730	-33	23.83	154	0.017	74	0.896	-17
		0.3	0.518	-80	15.52	122	0.037	61	0.647	-33
		0.5	0.382	-103	10.52	106	0.049	60	0.517	-34
		0.7	0.319	-122	7.89	96	0.060	61	0.450	-35
		0.9	0.287	-137	6.28	89	0.072	62	0.414	-35
		1.0	0.279	-144	5.71	86	0.078	63	0.402	-35
		1.3	0.268	-159	4.49	79	0.096	64	0.374	-36
		1.5	0.269	-168	3.94	74	0.108	64	0.362	-38
		2.0	0.278	176	3.02	64	0.139	63	0.343	-42
		2.5	0.294	161	2.48	55	0.171	61	0.331	-49
		3.0	0.311	151	2.12	47	0.202	59	0.323	-56
		3.5	0.329	142	1.86	39	0.233	56	0.319	-63
		4.0	0.347	134	1.68	31	0.265	53	0.314	-71
		4.5	0.367	127	1.53	24	0.298	51	0.309	-79
		5.0	0.390	120	1.42	18	0.332	47	0.305	-87
6.0	5.0	0.1	0.870	-20	14.57	163	0.016	79	0.958	-10
		0.3	0.719	-55	11.68	136	0.040	64	0.822	-23
		0.5	0.566	-76	8.81	118	0.053	58	0.697	-28
		0.7	0.457	-94	6.96	106	0.063	56	0.619	-30
		0.9	0.387	-109	5.69	98	0.072	56	0.571	-31
		1.0	0.365	-115	5.22	94	0.076	56	0.554	-32
		1.3	0.320	-133	4.18	84	0.089	57	0.516	-33
		1.5	0.306	-143	3.69	79	0.098	58	0.501	-35
		2.0	0.291	-164	2.86	67	0.121	59	0.476	-39
		2.5	0.293	178	2.35	57	0.146	60	0.462	-45
		3.0	0.304	165	2.02	48	0.171	59	0.454	-51
		3.5	0.319	154	1.78	40	0.198	59	0.452	-58
		4.0	0.339	145	1.60	32	0.228	58	0.449	-65
		4.5	0.359	136	1.46	25	0.261	56	0.445	-72
		5.0	0.384	128	1.35	18	0.297	54	0.442	-80

Table 1. Common Emitter S-Parameters (continued)

V _{CE} (Vdc)	I _C (mA)	f (GHz)	S ₁₁		S ₂₁		S ₁₂		S ₂₂	
			S ₁₁	∠ φ	S ₂₁	∠ φ	S ₁₂	∠ φ	S ₂₂	∠ φ
6.0	15.0	0.1	0.698	-37	28.78	150	0.014	74	0.877	-17
		0.3	0.465	-84	17.38	118	0.030	63	0.627	-29
		0.5	0.331	-105	11.47	103	0.041	64	0.525	-28
		0.7	0.274	-123	8.50	95	0.052	66	0.478	-27
		0.9	0.248	-137	6.74	88	0.063	67	0.453	-27
		1.0	0.241	-143	6.12	85	0.069	67	0.443	-27
		1.3	0.232	-158	4.80	78	0.086	68	0.425	-28
		1.5	0.235	-165	4.20	74	0.098	68	0.415	-30
		2.0	0.247	179	3.22	64	0.127	66	0.400	-34
		2.5	0.264	165	2.64	55	0.156	64	0.390	-41
		3.0	0.279	156	2.25	48	0.185	62	0.385	-47
		3.5	0.297	148	1.98	40	0.214	60	0.381	-54
		4.0	0.317	141	1.78	33	0.245	57	0.376	-61
		4.5	0.338	134	1.62	26	0.276	55	0.371	-69
		5.0	0.361	127	1.50	19	0.310	52	0.366	-76
	30.0	0.1	0.550	-54	35.24	141	0.012	70	0.801	-20
		0.3	0.351	-107	17.63	109	0.024	66	0.562	-25
		0.5	0.267	-130	11.12	97	0.035	70	0.506	-21
		0.7	0.246	-147	8.12	90	0.047	72	0.481	-21
		0.9	0.239	-158	6.39	84	0.058	72	0.467	-22
		1.0	0.239	-163	5.79	82	0.064	73	0.462	-22
		1.3	0.245	-174	4.52	75	0.082	72	0.450	-24
		1.5	0.253	-180	3.96	71	0.094	72	0.444	-26
		2.0	0.272	168	3.04	62	0.123	70	0.433	-32
		2.5	0.296	156	2.48	53	0.152	68	0.425	-39
		3.0	0.315	148	2.12	45	0.182	66	0.421	-46
		3.5	0.339	140	1.86	38	0.213	64	0.417	-54
		4.0	0.358	134	1.67	31	0.245	62	0.414	-61
		4.5	0.381	127	1.52	24	0.279	59	0.410	-69
		5.0	0.406	120	1.40	18	0.317	56	0.406	-77

Table 2. Common Emitter Noise Parameters

V _{CE} (Vdc)	I _C (mA)	f (GHz)	NF _{min} (dB)	Γ _o		R _N (Ω)	r _n	G _{NF} (dB)
				Magnitude	Angle			
1.0	1.0	0.3	1.14	0.67	16	29	0.58	17.3
		0.5	1.24	0.63	28	28	0.56	14.8
		0.7	1.35	0.60	40	27	0.53	12.5
		0.9	1.50	0.57	52	25	0.51	10.6
		1.0	1.57	0.56	58	24	0.49	9.7
		1.5	1.86	0.51	89	19	0.39	6.5
		2.0	2.08	0.50	120	13	0.26	5.2
3.0	3.0	0.3	1.04	0.57	12	21	0.42	21.5
		0.5	1.12	0.53	21	20	0.41	18.8
		0.7	1.21	0.50	31	19	0.39	16.4
		0.9	1.30	0.47	42	19	0.38	14.3
		1.0	1.34	0.45	47	18	0.37	13.4
		1.5	1.57	0.41	77	15	0.31	9.9
		2.0	1.80	0.40	110	12	0.24	8.4
6.0	5.0	0.3	1.22	0.54	11	22	0.44	23.1
		0.5	1.27	0.51	19	21	0.42	20.3
		0.7	1.32	0.48	28	20	0.41	17.8
		0.9	1.38	0.45	38	20	0.39	15.7
		1.0	1.41	0.44	43	19	0.38	14.7
		1.5	1.61	0.40	71	17	0.33	11.2
		2.0	1.86	0.38	103	13	0.26	9.5

Table 3. Spice Parameters (MRF949 Die Gummel-Poon Parameters)

Name	Value	Name	Value	Name	Value
IS	4.598E-16	IRB	8.00E-05	TF	1.00E-11
BF	175	RBM	3.0	XTF	50
NF	0.9904	RE	0.45	VTF	1.2
VAF	22	RC	6.0	ITF	0.32
IKF	0.08	XTB	0	PTF	32
ISE	1.548E-14	EG	1.11	TR	1.00E-09
NE	1.703	XTI	3.0	FC	0.9
BR	76.1	CJE	8.70E-13		
NR	0.9952	VJE	0.905		
VAR	2.1	MJE	0.389		
IKR	0.02059	CJC	3.60E-13		
ISC	3.395E-16	VJC	0.4907		
NC	1.13	MJC	0.2198		
RB	8.0	XCJC	0.43		

Figure 19. MRF949 SC-90/SC-75 Package Equivalent Circuit

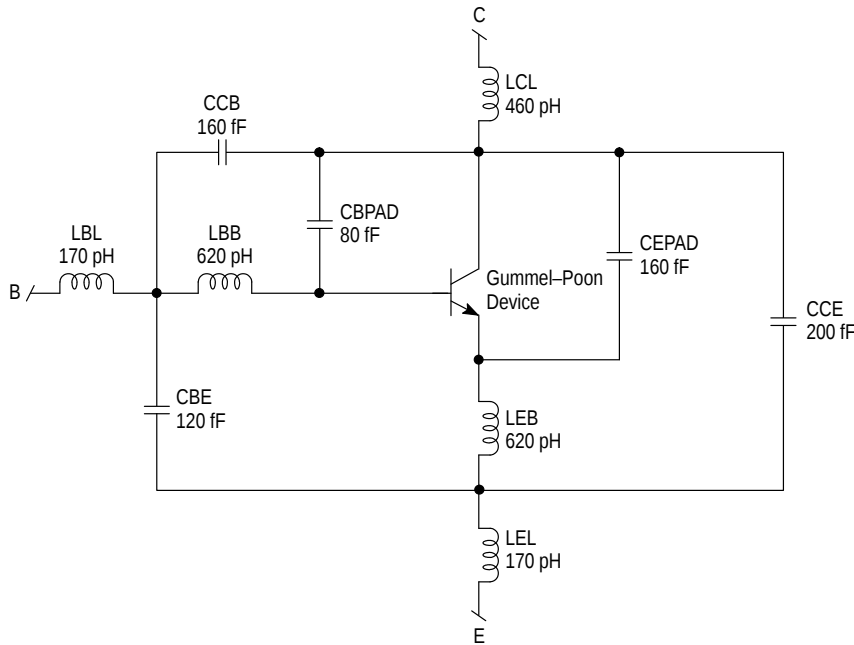


Figure 20. Constant Gain and Noise Figure Contours
(f = 1.0 GHz)

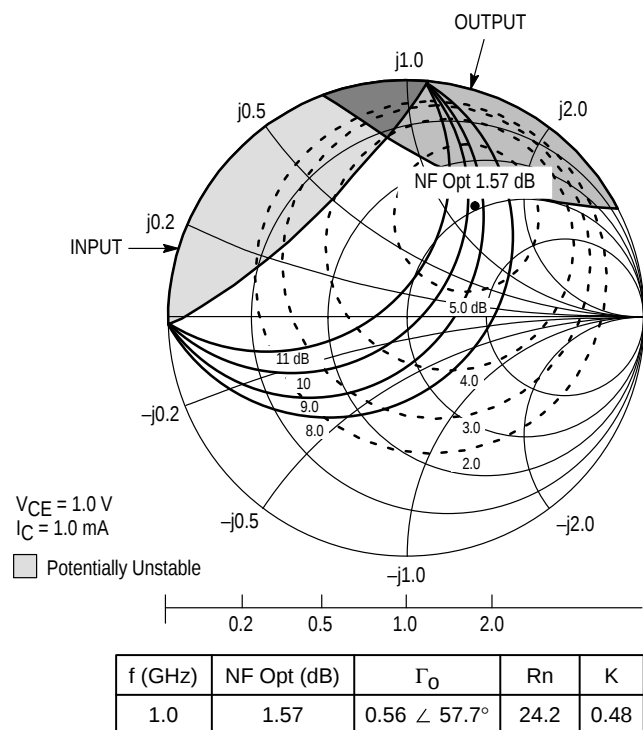


Figure 21. Constant Gain and Noise Figure Contours
(f = 2.0 GHz)

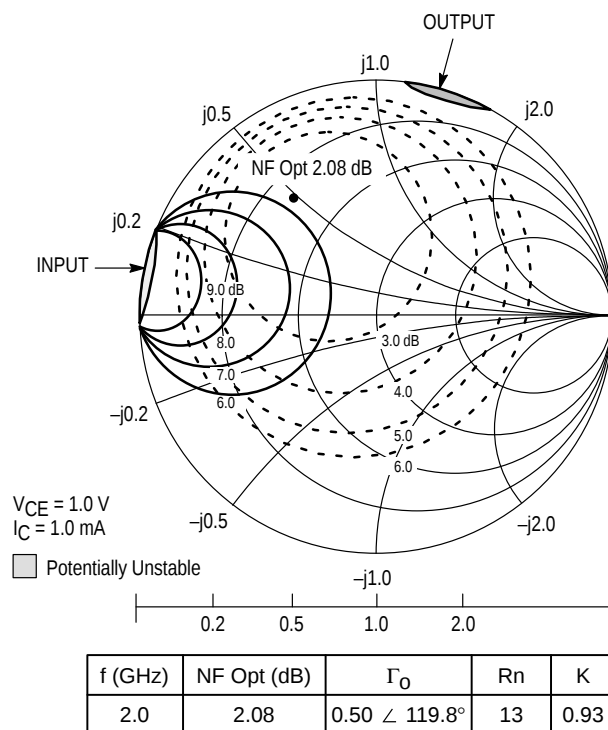


Figure 22. Constant Gain and Noise Figure Contours
(f = 1.0 GHz)

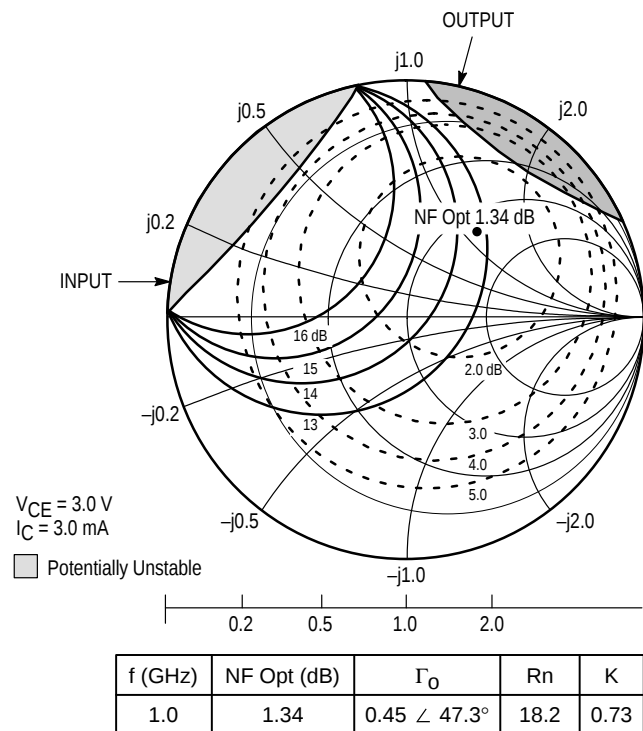
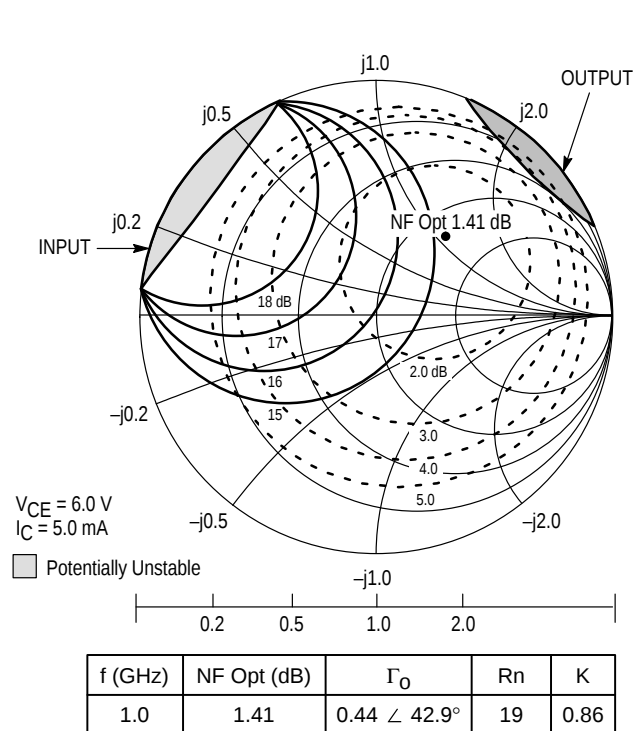


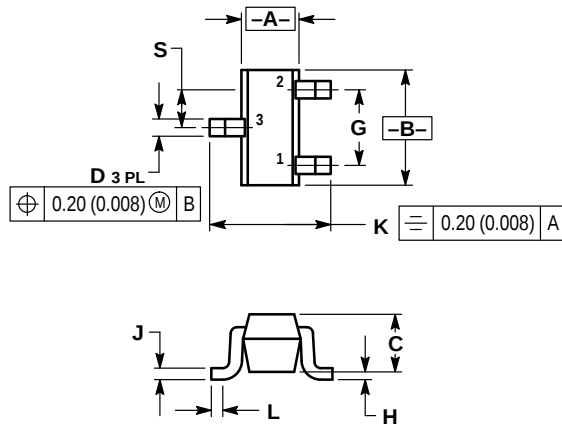
Figure 23. Constant Gain and Noise Figure Contours
(f = 1.0 GHz)



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OUTLINE DIMENSIONS

PLASTIC PACKAGE
CASE 463-01
(SC-90/SC-75)
ISSUE A



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.70	0.80	0.028	0.031
B	1.40	1.80	0.055	0.071
C	0.60	0.90	0.024	0.035
D	0.15	0.30	0.006	0.012
G	1.00 BSC		0.039 BSC	
H	—		0.10	
J	0.10	0.25	0.004	0.010
K	1.45	1.75	0.057	0.069
L	0.10	0.20	0.004	0.008
S	0.50 BSC		0.020 BSC	

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